

1 S 2363		Si-Di	=1S2361: 600V	31a	DO-27			BY 126...127, BY 133...134, 1N4005...07, ++
1 S 2364		Si-Di	=1S2361: 800V	31a	DO-27			BY 127, BY 133, BY 227, 1N4006...07, ++
1 S 2365		Si-Di	=1S2361: 1000V	31a	DO-27			BY 127, BY 133, BY 227, 1N4007, ++
1 S 2366	Shi	Si-Di	Rr, S, 200V, 0,1A, Uf<1,5V(0,1A), <1,5µs	31a	DO-14	BA 159	31a	BA 157...159, BAY 88...91, BY 203/12, ++
1 S 2367		Si-Di	=1S2366: 600V	31a	DO-14	BA 159	31a	BA 158...159, BAY 89...91, BY 203/12, ++
1 S 2368		Si-Di	=1S2366: 800V	31a	DO-14	BA 159	31a	BA 159, BAY 90...91, BY 203/12, ++
1 S 2369		Si-Di	=1S2368: 1000V	31a	DO-14	BA 159	31a	BA 159, BAY 90...91, BY 203/12, ++
1 S 2370		Si-Di	=1S2366: 1500V	31a	DO-14	BY 203/12	31a	BAY 91, BY 203/12, BY 584, SHG 1.5, ++
1 S 2371(A)	Shi	Si-Br	Br Rr, 100V, 1A, Uf<1,05V(0,5A)	(A: 20x5x8mm)	(20x8x8mm)	B250C1500	8, 33	B250C1500, etc.
1 S 2372(A)		Si-Br	=1S2371: 200V		(20x8x8mm)	B250C1500	8, 33	B250C1500, etc.
1 S 2373(A)		Si-Br	=1S2371: 400V		(20x8x8mm)	B250C1500	8, 33	B250C1500, etc.
1 S 2374(A)		Si-Br	=1S2371: 600V		(20x8x8mm)	B250C1500	8, 33	B250C1500, etc.
1 S 2375(A)		Si-Br	=1S2371: contr.av., 200V		(20x8x8mm)			-
1 S 2376(A)		Si-Br	=1S2371: contr.av., 400V		(20x8x8mm)			-
1 S 2377	Shi	Si-Di	Dual, Rr, 100V, 1,8A, Uf<1,05V(0,9)	12j	(12x15x5)			2x (BY 226...227, BY 251...255, 1N5060, ++)
1 S 2378		Si-Di	=1S2377: 200V	12j	(12x15x5)			2x (BY 226...227, BY 251...255, 1N5060, ++)
1 S 2379		Si-Di	=1S2377: 400V	12j	(12x15x5)			2x (BY 226...227, BY 252...255, 1N5060, ++)
1 S 2380		Si-Di	=1S2377: 600V	12j	(12x15x5)			2x (BY 226...227, BY 253...255, 1N5061, ++)
1 S 2377R...2380R		Si-Di	=1S2377:	12h	(12x15x5)			2x (BY 226...227, BY 251...255, 1N5061, ++)
1 S 2381	Shi	Si-Di	Dual, Rr, 100V, 1A, Uf<1,05V(0,5A)	12j	(12x15x5)			2x (BY 126...127, BY 133...135, 1N4002, ++)
1 S 2382		Si-Di	=1S2381: 200V	12j	(12x15x5)			2x (BY 126...127, BY 133...134, 1N4003, ++)
1 S 2383		Si-Di	=1S2381: 400V	12j	(12x15x5)			2x (BY 126...127, BY 133...134, 1N4004, ++)
1 S 2384		Si-Di	=1S2381: 600V	12j	(12x15x5)			2x (BY 126...127, BY 133...134, 1N4005, ++)
1 S 2387 H	Hit	Si-Di	SS, 120/130V, 0,25/0,75A, Uf<1,2V(0,1A), <10ns	31a	DO-35			BA 203, BAV 14
1 S 2390	Nec	Si-Di	Rr, 50V, 1A, Uf<1V(1A)	31a	SOD-57			BY 126...127, BY 133...135, 1N4001...07, ++
1 S 2391		Si-Di	=1S2390: 100V	31a	SOD-57			BY 126...127, BY 133...135, 1N4002...07, ++
1 S 2392		Si-Di	=1S2390: 200V	31a	SOD-57			BY 126...127, BY 133...134, 1N4003...07, ++
1 S 2393		Si-Di	=1S2390: 300V	31a	SOD-57			BY 126...127, BY 133...134, 1N4004...07, ++
1 S 2394		Si-Di	=1S2390: 400V	31a	SOD-57			BY 126...127, BY 133...134, 1N4004...07, ++
1 S 2395		Si-Di	=1S2390: 500V	31a	SOD-57			BY 126...127, BY 133...134, 1N4003...07, ++
1 S 2396		Si-Di	=1S2390: 600V	31a	SOD-57			BY 126...127, BY 133...134, 1N4005...07, ++
1 S 2397		Si-Di	=1S2390: 700V	31a	SOD-57			BY 127, BY 133, BY 227, 1N4006...07, ++
1 S 2398		Si-Di	=1S2390: 800V	31a	SOD-57			BY 127, BY 133, BY 227, 1N4006...07, ++
1 S 2399		Si-Di	=1S2390: 900V	31a	SOD-57			BY 127, BY 133, BY 227, 1N4007, ++
1 S 2400		Si-Di	=1S2390: 1000V	31a	SOD-57			BY 127, BY 133, BY 227, 1N4007, ++
1 S 2401	Mit	Si-Di	Rr, 100V, 1A, Uf<1,2V(3A)	31a	DO-15			BY 126...127, BY 133...135, 1N4002...07, ++
1 S 2402		Si-Di	=1S2401: 200V	31a	DO-15			BY 126...127, BY 133...134, 1N4003...07, ++
1 S 2403		Si-Di	=1S2401: 400V	31a	DO-15			BY 126...127, BY 133...134, 1N4004...07, ++
1 S 2404		Si-Di	=1S2401: 600V	31a	DO-15			BY 126...127, BY 133...134, 1N4005...07, ++
1 S 2405		Si-Di	=1S2401: 800V	31a	DO-15			BY 127, BY 133, BY 227, 1N4006...07, ++
1 S 2406		Si-Di	=1S2401: 1000V	31a	DO-15			BY 127, BY 133, BY 227, 1N4007, ++
1 S 2407		Si-Di	=1S2401: 1200V	31a	DO-15			BY 127, BY 133, BY 227, GP 10Q, ++
1 S 2408	Mit	Si-Di	Rr, 50V, 2A, Uf<1,1V(10A)	31a	SOD-18			BY 226...227, BY 251...255, 1N5060...62, ++
1 S 2409		Si-Di	=1S2408: 100V	31a	SOD-18			BY 226...227, BY 251...255, 1N5060...62, ++
1 S 2410		Si-Di	=1S2408: 200V	31a	SOD-18			BY 226...227, BY 251...255, 1N5060...62, ++
1 S 2411		Si-Di	=1S2408: 300V	31a	SOD-18			BY 226...227, BY 252...255, 1N5060...62, ++
1 S 2412		Si-Di	=1S2408: 400V	31a	SOD-18			BY 226...227, BY 252...255, 1N5060...62, ++
1 S 2413		Si-Di	=1S2408: 500V	31a	SOD-18			BY 226...227, BY 253...255, 1N5061...62, ++
1 S 2414		Si-Di	=1S2408: 600V	31a	SOD-18			BY 226...227, BY 253...255, 1N5061...62, ++
1 S 2415	Mit	Si-Di	Rr, 50V, 2A, Uf<1,1V(10A)	31a	SOD-18			BY 226...227, BY 251...255, 1N5060...62, ++
1 S 2416		Si-Di	=1S2415: 100V	31a	SOD-18			BY 226...227, BY 251...255, 1N5060...62, ++
1 S 2417		Si-Di	=1S2415: 200V	31a	SOD-18			BY 226...227, BY 251...255, 1N5060...62, ++
1 S 2418		Si-Di	=1S2415: 300V	31a	SOD-18			BY 226...227, BY 252...255, 1N5060...62, ++
1 S 2419		Si-Di	=1S2415: 400V	31a	SOD-18			BY 226...227, BY 252...255, 1N5060...62, ++
1 S 2420		Si-Di	=1S2415: 500V	31a	SOD-18			BY 226...227, BY 253...255, 1N5061...62, ++
1 S 2421		Si-Di	=1S2415: 600V	31a	SOD-18			BY 226...227, BY 253...255, 1N5061...62, ++
1 S 2422	Mit	Si-Di	P Rr, 50V, 20A(Tc=115°), Uf<1,2V(40A)	75a	DO-21			1N3491...3495
1 S 2423		Si-Di	=1S2422: 100V	75a	DO-21			1N3492...3495
1 S 2424		Si-Di	=1S2422: 200V	75a	DO-21			1N3493...3495
1 S 2425		Si-Di	=1S2422: 300V	75a	DO-21			1N3494...3495
1 S 2426		Si-Di	=1S2422: 400V	75a	DO-21			1N3495
1 S 2427		Si-Di	=1S2422: 500V	75a	DO-21			-
1 S 2422R...2427R		Si-Di	=1S2422:	75b	DO-21			DS 25...A
1 S 2428(R)	Mit	Si-Di	P Rr, 50V, 15A(Tc=115°), Uf<1,2V(40A)					-
1 S 2429(R)		Si-Di	=1S2428: 100V					-
1 S 2430(R)		Si-Di	=1S2428: 200V					-
1 S 2431(R)		Si-Di	=1S2428: 300V					-
1 S 2432(R)		Si-Di	=1S2428: 400V					-
1 S 2433(R)		Si-Di	=1S2428: 500V					-
1 S 2434	Mit	Si-Di	P Rr, 50V, 12A(Tc=120°), Uf<1,2V(40A)	32a	=DO-5			1N3765...3768, 1N4525...4530
1 S 2435		Si-Di	=1S2434: 100V	32a	=DO-5			1N3765...3768, 1N4525...4530
1 S 2436		Si-Di	=1S2434: 200V	32a	=DO-5			1N3765...3768, 1N4525...4530
1 S 2437		Si-Di	=1S2434: 300V	32a	=DO-5			1N3765...3768, 1N4526...4530
1 S 2438		Si-Di	=1S2434: 400V	32a	=DO-5			1N3765...3768, 1N4526...4530
1 S 2439		Si-Di	=1S2434: 500V	32a	=DO-5			1N3765...3768, 1N4527...4530
1 S 2434R...2439R		Si-Di	=1S2434:	32b	=DO-5			D24/...C, 1N3765R...3768R
1 S 2440	Mit	Si-Di	P Rr, 50V, 25A(Tc=120°), Uf<1,2V(80A)	75a	DO-21			1N3491...3495
1 S 2441		Si-Di	=1S2440: 100V	75a	DO-21			1N3492...3495
1 S 2442		Si-Di	=1S2440: 200V	75a	DO-21			1N3493...3495
1 S 2443		Si-Di	=1S2440: 300V	75a	DO-21			1N3494...3495
1 S 2444		Si-Di	=1S2440: 400V	75a	DO-21			1N3495
1 S 2445		Si-Di	=1S2440: 500V	75a	DO-21			-
1 S 2440R...2445R		Si-Di	=1S2440:	75b	DO-21			DS 25...A
1 S 2446	Mit	Si-Di	P Rr, 50V, 25A(Tc=120°), Uf<1,2V(80A)	32a	=DO-5			1N3765...3768, 1N4525...4530
1 S 2447		Si-Di	=1S2446: 100V	32a	=DO-5			1N3765...3768, 1N4525...4530
1 S 2448		Si-Di	=1S2446: 200V	32a	=DO-5			1N3765...3768, 1N4525...4530
1 S 2449		Si-Di	=1S2446: 300V	32a	=DO-5			1N3765...3768, 1N4526...4530
1 S 2450		Si-Di	=1S2446: 400V	32a	=DO-5			1N3765...3768, 1N4526...4530
1 S 2451		Si-Di	=1S2446: 500V	32a	=DO-5			1N3765...3768, 1N4527...4530
1 S 2445R...2451R		Si-Di	=1S2446:	32b	=DO-5			D24/...C, 1N3765R...3768R
1 S 2452	Tos	Ref-Di	6...7V(10mA), ±0,01%/°C, <15Ω, 0,25W	2c	TO-18			BZV 10, BZV 27, 1N4580
1 S 2453		Ref-Di	=1S2452: ±0,005%/°C	2c	TO-18			BZV 11, BZV 28, 1N4581
1 S 2454		Ref-Di	=1S2452: ±0,002%/°C	2c	TO-18			BZV 12, BZV 29, 1N4582